General purpose transistor (50V, 0.15A) 2SC2412K / 2SC4081 / 2SC4617 / 2SC5658 / 2SC1740S

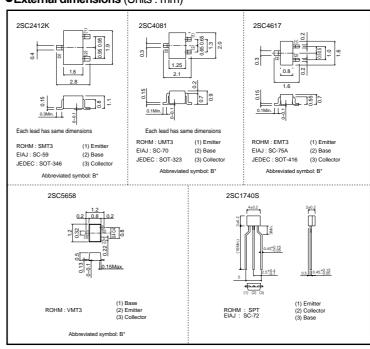
● Features

- 1) Low Cob. Cob=2.0pF (Typ.)
- 2) Complements the 2SA1037AK / 2SA1576A / 2SA1774H / 2SA2029 / 2SA933AS.

Structure

Epitaxial planar type NPN silicon transistor

●External dimensions (Units : mm)



^{*} Denotes hre

● Absolute maximum (Ta=25°C)

Parameter		Symbol	Limits	Unit	
Collector-base voltage		Vсво	60	V	
Collector-emitter voltage		Vceo	50	V	
Emitter-base voltage		VEBO	7	V	
Collector current		Ic	0.15	Α	
Collector power dissipation	2SC2412K, 2SC4081		0.2	W	
	2SC4617, 2SC5658	Pc	0.15		
	2SC1740S		0.3		
Junction temperature		Tj	150	°C	
Storage temperature		Tstg	-55~+150	°C	

●Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Collector-base breakdown voltage	ВУсво	60	_	_	V	Ic=50μA
Collector-emitter breakdown voltage	BVceo	50	_	_	V	Ic=1mA
Emitter-base breakdown voltage	ВVево	7	_	_	V	Iε=50μA
Collector cutoff current	Ісво	_	_	0.1	μΑ	Vcb=60V
Emitter cutoff current	ІЕВО	_	_	0.1	μΑ	V _{EB} =7V
DC current transfer ratio	hfe	120	_	560	_	Vce=6V, Ic=1mA
Collector-emitter saturation voltage	VCE(sat)	_	_	0.4	V	Ic/I _B =50mA/5mA
Transition frequency	f⊤	_	180	_	MHz	VcE=12V, IE=-2mA, f=100MHz
Output capacitance	Cob	-	2	3.5	pF	Vce=12V, Ie=0A, f=1MHz

●Packaging specifications and hFE

		Package	Taping			Bulk	
		Code	T146	T106	TL	T2L	TP
Туре	hfe	Basic ordering unit (pieces)	3000	3000	3000	8000	5000
2SC2412K	QRS		0	-	-	_	-
2SC4081	QRS		-	0	-	-	-
2SC4617	QRS		-	_	0	-	_
2SC5658	QRS		-	_	_	0	_
2SC1740S	QRS		-	_	_	_	0

hre values are classified as follows:

Item	Q	R	S
hfe	120~270	180~390	270~560

●Electrical characterristic curves

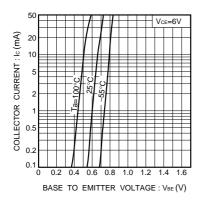


Fig.1 Grounded emitter propagation characteristics

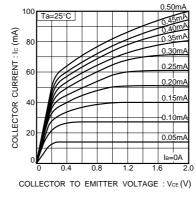


Fig.2 Grounded emitter output characteristics (I)

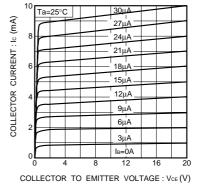


Fig.3 Grounded emitter output characteristics (II)

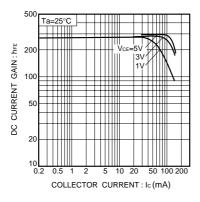


Fig.4 DC current gain vs. collector current (I)

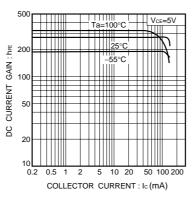


Fig.5 DC current gain vs. collector current (II)

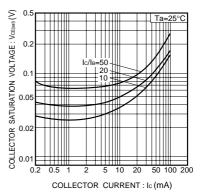


Fig. 6 Collector-emitter saturation voltage vs. collector current

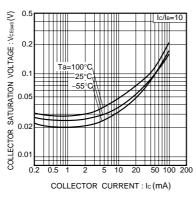


Fig.7 Collector-emitter saturation voltage vs. collector current (I)

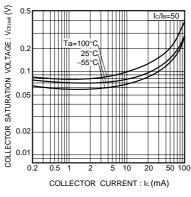


Fig.8 Collector-emitter saturation voltage vs. collector current (II)

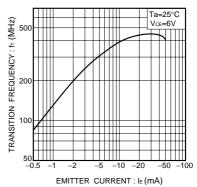


Fig.9 Gain bandwidth product vs. emitter current

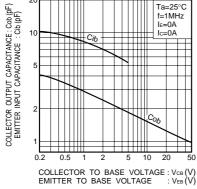


Fig.10 Collector output capacitance vs. collector-base voltage Emitter input capacitance vs. emitter-base voltage

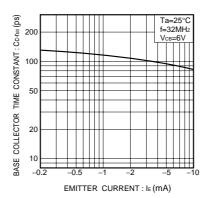


Fig.11 Base-collector time constant vs. emitter current

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